Parametric resonance of acoustic and optical phonons in a doped semiconductor superlattice

Phong T.C., Tung L.V., Bau N.Q.
Department of Physics, College of Education, Hue University, 32 Le Loi, Hue, Viet Nam; Department of Physics, Dong Thap University of Education, 783 Pham Huu Lau, Cao Lanh, Dong Thap, Viet Nam; Department of Physics, Hanoi National University, 334-Nguyen Trai, Thanh Xuan, Hanoi, Viet Nam

Abstract: The parametric resonance of acoustic and optical phonons in a doped superlattice with a non-degenerative electron gas in the presence of a laser field is theoretically predicted by using a set of quantum transport equations for the phonons. Dispersions of the resonant phonon frequency and the threshold amplitude of the field for parametric amplification of the acoustic phonons are obtained. The amplitude is also estimated for realistic semiconductor models.

Author Keywords: Acoustic phonon; Doped semiconductor superlattice; Optical phonon; Parametric resonance

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Correspondence Address: Phong, T. C.; Department of Physics, College of Education, Hue University, 32 Le Loi, Hue, Viet Nam; email: congphong2000@yahoo.com
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Authors with affiliations:
- Phong, T.C., Department of Physics, College of Education, Hue University, 32 Le Loi, Hue, Viet Nam
- Tung, L.V., Department of Physics, Dong Thap University of Education, 783 Pham Huu Lau, Cao Lanh, Dong Thap, Viet Nam
- Bau, N.Q., Department of Physics, Hanoi National University, 334-Nguyen Trai, Thanh Xuan, Hanoi, Viet Nam

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